

Investigation of strain relaxation mechanism in Si-SiO₂ system during the process of its formation

Kropman, Daniel; Poll, V.; Kämer, T.; Ugaste, Ülo; Mellikov, Enn; Arbu, Uno; Paomets, V. Physica status solidi (a) 2003 / 2, p. 297-301 <https://onlinelibrary.wiley.com/doi/abs/10.1002/pssa.200306611>

Ultra-fast turn-on medium power thyristor

Vaher, G.; Udal, Andres; Typpö, J.; Paomets, V.; Sivonen, M. BEC : Baltic Electronics Conference : proceedings of the 4th Biennial Conference, October 9-14, 1994, Tallinn (Estonia). 2 1994 / p. 567-572: ill https://www.ester.ee/record=b2150914*est

Ultra-fast-turn-on medium power double thyristor

Vaher, G.; Udal, Andres; Sivonen, M.; Paomets, V. ESSDERC'95 : proceedings of the 25th European Solid State Device Research Conference, the Netherlands Congress Centre, the Hague, the Netherlands, 25th-27th September 1995 1995 / p. 647-650: ill

Определение радиоактивности методом ионизации

Paomets, V.; Meitre, Johannes Сборник научных трудов студентов. 3 1960 / с. 65-69 : илл

https://www.ester.ee/record=b2181418*est <https://digikogu.taltech.ee/et/Item/3c57b85a-ce7a-4beb-ab6a-4e0c682a1d0b>